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A Minimal Growth Equation For Conservative Non Equilibrium Growth From Vapor

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A continuum growth equation in 1+1 dimensions is obtained by considering the contributions to the underlying current from kinetics of adatoms on the surface . These considerations reproduce the slope dependent term that represents a stable or an unstable growth depending on the sign of the associated coefficient. In addition an $h \to -h$ symmetry breaking nonlinear term is obtained. Implications of this term on the stable→ unstable growth transition are discussed. This term is tilt independent and is expected to be present independent of the source of the current in the conserved growth. computer simulation based on a zero diffusion bias model is used to verify some of the predictions of the minimal growth equation. It is shown that the growth equations for cellular automata type models involving instantaneous relaxations can be obtained from the proposed method by addressing the corresponding kinetics of adatoms.

A continuum description of conserved growth from vapor is obtained from Langevin type equation $\partial_t h + \nabla \cdot \mathbf{J} = F$ where $h(\mathbf{r},t)$ is height function , $\mathbf{J}$ is current due to adatom relaxation on the growing surface and F is the average flux with white noise. The current $\mathbf{J}$ includes an equilibrium and a nonequilibrium(NE) contribution. Most of the experimental growth is far from equilibrium and has been studied over last many years [1,2]. Description of such growth is essentially through the nonequilibrium current $\mathbf{J}_{NE}$. The contributing terms to $\mathbf{J}_{NE}$ are obtained by comparing the behaviour of growth equation containing sets of different terms, satisfying required symmetry and invariances of the problem, with the experimental observations [3,4] or, appealing to the underlying kinetics [5,6]. Former is an empirical approach while later, a direct approach. It is desired that from kinetic considerations , $\mathbf{J}_{NE}$ could be constructed, describing the experimental observations.Such an approach was adopted by Villain [6] earlier. In reference [6], from computer based solutions of the equations describing step velocities in 1+1 dimensions, and the consequent interface profiles, it was concluded that the local form of the growth equation should comprise of a) a term of the form $\frac{\pm m}{(1+a'|m|)(1+b'|m|)}$ where a' and b' are constants, related to the diffusion kinetics, b) an $h \to -h$ symmetry breaking term and c) a term of the form $\nabla^4 h$.

In what follows we show that these terms can be *derived* by appropriately identifying the kinetic processes that contribute to the nonequilibrium current. To our knowledge the method proposed in this work has not been used to obtain $\mathbf{J}_{NE}$ in any of the previous work related to growth from vapor. Most of our discussion will be pivoted around the symmetry breaking term that assumes the form $\nabla^2(\nabla h)^2$ for small inclinations while at large slopes takes the form $\frac{1}{m^3}\partial_x m$ thus unifying the descriptions [2,6] at small and large slopes. While obtaining the NE contributions to the current, we will consider growth with Schwoebel-Ehrlich (SE) [7] barrier to account the stable as well as unstable growth. However the method of obtaining these contributions can be applied to any other models not employing the SE barrier [8,9]. We have applied it later to a stochastic model with cellular automata type rules that mimic the molecular beam epitaxial (MBE) growth at low temperature [10] referred in the literature as DT model.

Consider growth on a 1 dimensional flat substrate with lattice constant a. We will consider the situation depicted in Fig. 1 for obtaining various contributions to the current where steps are such that positive slope is obtained. Adatoms are randomly deposited on the substrate. Let D_s be the diffusion constant on the terrace, l_c be the average distance that an adatom travels on a terrace before encountering another adatom. Detachment from steps or nuclei on the terrace is negligible. Adatoms hopping down the descending steps contribute to the downward current j_d while those hopping on the terrace can get attached to an ascending step contribute to the in-plane current j_i. Referring to Fig. 1 , the adatoms reaching site A and hopping down the step to the left constitute j_d and those reaching site B and hopping to the right towards the ascending step constitute j_i. The net current is $j_d + j_i$. These are obtained as follows,

$j_{d(i)}$=(local density of site A(B))·(flux of adatoms approaching A(B))·(probability for hopping across A(B)).

(1)

Since the relaxation of adatoms is through the diffusion on the terrace or across the step edges, the density of sites A and B is same as density of steps which is approximately given by $\frac{|m|}{1+|m|}$, where m is the local slope.

In the absence of nucleation, lateral flux(LF) approaching site B or A is $\frac{\pm \hat{n} F}{2|m|a^{-1}}$, $a|m|^{-1}$ being the average local terrace width and $\hat{n}$ is unit vector in the x direction. When terrace size is large enough, this flux is restricted due to the nucleation. The nucleation process will restrict the diffusion to an average length l_c on a large terrace.

As a result, even for very large terraces, the approaching flux LF is almost constant. The effect of nucleation is incorporated by introducing l_c in the expression for LF as $\frac{\hat{n}F}{2(l_c^{-1}+|m|a^{-1})}$, so that for small slopes the expression is reduced to a constant value. Let P_A and P_B represent the probabilities of hopping across sites A and B respectively. The Schwoebel length [5] $l_s \propto (P_B - P_A)$. Hence from the Eq.(1) the current is

$$\mathbf{j}_s = \frac{\hat{n}|m|F(P_B - P_A)}{2(1+|m|)(l_c^{-1} + |m|a^{-1})} \tag{2}$$

The LF approaching sites A and B is however modified due to the relative motion of the steps. Consider the situation in Fig.1 where v is the velocity of the step bearing the terrace while v' that of the higher one on the positive slope. For $v' > v$ the terrace width is reduced, depleting the LF approaching sites A and B. The reduction in flux is $\propto \delta v$ where $\delta v = (v' - v)$. Adatoms hopping across upper step as well as those attaching in-plane, both contribute to the velocity of the step. Thus the velocity $v \propto j_s$ except that the coefficient $(P_B - P_A)$ is replaced by $(P_A + P_B)$. Hence $\delta v \propto \frac{(P_A+P_B)}{l_c^{-1}+|m|a^{-1}}\partial_x \frac{|m|}{2(1+|m|)(l_c^{-1}+|m|a^{-1})}$. Corresponding current *will not depend on* $(P_B - P_A)$ since this part of the flux is removed from the LF. The current is therefore obtained by multiplying the LF by density of steps. P_A and P_B are relative probabilities so that $P_A + P_B = 1$. Accounting for this effect the expression for the current becomes,

$$\begin{aligned}\mathbf{j}(x) = {} & \frac{\hat{n}|m|F(P_B - P_A)}{2(1+|m|)(l_c^{-1} + |m|a^{-1})} \\ & - \frac{\hat{n}|m|F}{(1+|m|)(l_c^{-1} + |m|a^{-1})} \\ & \partial_x \left(\frac{|m|}{2(1+|m|)(l_c^{-1} + |m|a^{-1})} \right)\end{aligned} \tag{3}$$

In the limit of small m, the current reduces to,

$$\mathbf{j}(x) = \hat{n}(P_B - P_A)|m|l_c/2 - \hat{n}l_c^{-1}\partial_x(m^2F) \tag{4}$$

The second term in general will have the form $\nabla(\nabla h)^2$. This term was derived using the Burton-Cabrera-Frank (BCF) theory and assuming that at small slopes the particle density on the terraces depends on the even powers of local gradient [2,6]. In the presnt case the difference in the velocities of two consecutive steps on a slope is related to the difference in the adatom densities on their terraces. However we do not explicitly assume the dependence of density on the even powers of slope. Further, in ref. [4] it was conjectured that such a term can arise due to the differences in the velocities of the steps near the top and the bottom of a profile.

In the limit of large slope, $|m|a^{-1} \gg l_c^{-1}$ the current reduces to,

$$\mathbf{j}(x) = \frac{\hat{n}(P_B - P_A)aF}{2|m|} - \frac{\hat{n}Fa^2}{2|m|}\partial_x \left(\frac{1}{|m|} \right) \tag{5}$$

The second term is proportional to $\frac{1}{m^3}\partial_x m$, which was derived in the large slope limit in reference [6]. Thus the geometrical dependence of the symmetry breaking term in Eq.(3) exactly matches with previously derived two terms in the small and large slope limits. This shows that present method of deriving current, appropriately accounts for the physical processes contributing to it.

We further argue that a curvature dependent current must be present in any adatom relaxation process that involves downward hops across the descending step edges. This argument is based on the observation that, in a 1+1 dimensional simulation, if adatoms are restricted completely to the in-plane hops (infinite SE barrier) then correlations do not grow beyond the diffusion length. On the other hand, when such hops are allowed, correlation length for stable growth and mound size for unstable growth increases in time [11]. Hence if the downward hops are allowed but the current is tilt-independent, then it may be expressed as a linear combination $a_1\nabla^3 h + a_2\nabla^5 h + ...$ including the nonlinear terms of the form $\nabla(\nabla^3 h)^2$. We will retain only $\nabla^3 h$ in the current corresponding to our minimal growth equation. Thus the form of the current corresponding to the minimal growth equation is

$$\begin{aligned}\mathbf{j}(x) = {} & \frac{\hat{n}|m|F(P_B - P_A)}{2(1+|m|)(l_c^{-1} + |m|a^{-1})} \\ & - \frac{\hat{n}|m|F}{2(1+|m|)(l_c^{-1} + |m|a^{-1})} \\ & \partial_x \left(\frac{|m|}{(1+|m|)(l_c^{-1} + |m|a^{-1})} \right) + k\frac{\partial^3 h}{\partial x^3}\end{aligned} \tag{6}$$

The first term has been studied widely as the stable growth mode [12,13] and as the unstable growth mode [14]. In order to find the effect of asymmetry term on the growth exclusively, we have performed simulations of a 1+1 dimensional solid-on-solid model with *no diffusion bias*. A fourth ordered equation was earlier proposed by Villain [5] for similar situation. Under this condition $P_A = P_B$ and first term vanishes in the Eq(3). The resultant growth equation in the moving frame with growth front is of the form,

$$\partial_t h = \nu\nabla^4 h + \nu_a \partial_x \left(\frac{m}{(1+|m|)((l_c^{-1} + |m|a^{-1})} \right)^2 + \eta \tag{7}$$

where, ν_a is the appropriate constant for the asymmetry term and η is white noise with $<\eta(x',t')\eta(x,t)> = D\delta(x'-x)\delta(t'-t)$. In the limit of small slopes, renormalization group (RG) analysis shows that the roughness exponent $\alpha = 1$ and the roughness evolves with the exponent $\beta = 1/3$ [4]. For large slopes, asymmetric term, on power counting leads to $z - 3\alpha$, while noise term gives $z - 1 - 2\alpha$. If ν_a is assumed to be invarient under renormalization, then again $\alpha = 1$ and $\beta = 1/3$ as in the case of small slope. Corresponding model is as follows. Atoms are rained on a 1-d substrate of length L randomly with constant flux. On deposition a given adatom is allowed to hop n times, as in a random walk. If the hopping adatom encounters another adatom before n hops are exausted, the adatom stays there permanently. If n hops are exausted without any encounter, it stays permanently at the last position occupied after n hops. Thus for hopping, all sites with zero neighbor are equivalent, ensuring $P_A = P_B$. We have measured width w_2, height- height correlations $G(\mathbf{r}, t)$ and skewness σ for this model where, $w_2 = \frac{1}{N}\sum_i (h_i - \bar{h}) \sim t^{2\beta}$ and $G(\mathbf{r}, t) = \frac{1}{N}\sum_{\mathbf{r}'}(h(\mathbf{r}+\mathbf{r}', t) - h(\mathbf{r}', t))^2$. The skewness $\sigma = w_3/w_2^{3/2}$, where $w_3 = \frac{1}{N}\sum_i (h_i - \bar{h})^3$ [15].

Presence of $\nabla^4 h$ term is verified from the flatness of the saturated width for small L. We have chosen, n=25 giving $l_c \approx 5$. The saturated width is flat almost up to $5l_c$, showing that $\nabla^4 h$ dominates at small lengths [6]. Fig. 2(a) shows the morphology of the interface after 80000ML are grown. As predicted by the Eq.(7), the asymmetry is evident in the figure with $\sigma = -0.47 \pm 0.05$. . Fig. 2(b) shows plot of w_2 in time. We obtain initially β around 0.3 that attains a steady value of 0.355 ± 0.015. Initial small value can be related to the small slope region that predicts a value of 1/3 (compare data in the region from 10 ML to 200 ML in the figure with the line having slope of 2/3). Correspondingly h-h correlations lead to the roughness exponent α that increases from 0.5 to 0.65 ± 0.01. These results indicate that most of the morphological features of the growth with diffusion without detachment are captured by the current expression in Eq.(6). It also shows that diffusion of the adatoms roughens the growing surface. Diffusion bias causes additional effects in terms of stability or instability of growth. In particular, if the bias is varied from extreme -ve SE barrier to extreme +ve SE barrier, a stable→ unstable transition is observed. In this transition however $h \rightarrow -h$ symmetry is broken asymptotically. Note that for -ve SE barrier $\nu_2 \nabla^2 h$ term dominates with +ve value of ν_2 [12], so that asymptotically, asymmetric term becomes irrelevant rendering $\sigma = 0$. At exactly zero SE barrier, finite value of $\sigma (\approx -0.5)$ is obtained. σ can be regarded as the symmetry parameter, that changes abruptly at the transition point. Thus the growth transition is like 2nd order phase transition. Details of such a transition in computer simulations of suitable models will be discussed elsewhere.

Extension of this equation to 2+1- dimensions is possible by similar kinetic considerations. For isotropic diffusion, same form as Eq.(6) is obtained with $\hat{n} = \nabla h/|\nabla h|$ and replacing length-derivative product in asymmetric term by $\frac{\nabla h \cdot \nabla}{(l_c^{-1} + |\nabla h|)|\nabla h|}$. For small slopes one obtains $\nabla(\nabla h)^2$ term [4] which seems to describe many experimentally observed growth roughness measurements from vapor [16].

As mentioned earlier, the present method for obtaining current from kinetic considerations appropriately brings out the geometrical dependence in growth equation. We have applied this method to one of the stochastic growth models proposed to capture the essential feature of low temperature molecular beam epitaxy (MBE) the DT model [10]. Based on noise reduction technique, the simulations of this model [17] confirm that, *1)* exponent $\beta = 3/8$, *2)* the morphology is asymmetric with $\sigma \approx -0.5$ and *3)* the current is tilt independent [2,17]. The observed β value of 3/8 is constant almost over 8 orders of magnitude [17]. The relaxation rules for adatom in this model allows it to hop only when it is deposited at site A or B (see Fig. 1). Also only downward hop is allowed, if deposited at A and towards the step, if deposited at B. If it has choice of sites A,A or B,B or A,B etc. on two neighboring sites, then it will hop randomly to the left or right. Applying the considerations for obtaining current for this situation shows that the LF approaching sites A or B in the present set of rules is $\frac{F}{a^{-1} + |m|a^{-1}}$, since the flux is affected only at large enough slope when site A and B overlap due to the short terrace width. Further, the LF is affected by relative motion of steps only when sites A and B differ by a lattice constant. The expression for the current is then,

$$J_{DT}(x) = -\nu \frac{\partial^2 m}{\partial x^2} - \frac{\hat{n} F a^2}{2} \frac{m}{1 + |m|} \partial_x \frac{m}{(1 + |m|)^2} \qquad (8)$$

From the rules it is clear that $P_A = P_B$. The growth equation corresponding to this current in the moving frame will be,

$$\partial_t h = \nu \frac{\partial^4 h}{\partial x^4} + \nu_a \partial_x \frac{m}{1 + |m|} \partial_x \frac{m}{(1 + |m|)^2} + \eta \qquad (9)$$

where, ν_a accounts for various constants in the corresponding expression for current. The power counting in this equation leads to , $z = 4$ from the first term, and $z = 1 + 2\alpha$ for large slopes corresponding to the second term which is expected to be operative mainly over large inclinations. The relation obtained from the second term is exactly same as the one obtainable from the noise term η. For $z = 4$ all the terms are marginal. This implies that $z = 4$ and $\beta = 3/8$. The second term is symmetry breaking. Hence, above equation accounts for all the observed facts mentioned above in the simulation of DT model. In 2+1-dimensions, with above rules for adatom relaxation, the local density of sites A and B need not be equal since, fluctuations in step edges render configurations that show bias for sites A or B. As a result, slope dependent current will dominate the growth [17]. Further implications of this equation are presently under study.

In conclusion, we have proposed a simple method for obtaining current in a solid-on-solid growth in 1+1- dimension. The resultant equation shows that presence of diffusion alone is resposible for roughning of a singular surface. It induces an asymmetric term in the continuum equation. As a result a stable to unstable transition will be associated with symmetry breaking. We have also demonstrated the application of this method of obtaining current to a stochastic model referred as DT model. The corresponding continuum equation is shown to predict observed exponents and the nature of the interface profile correctly.

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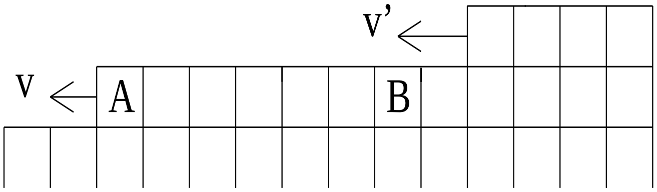

FIG. 1. A typical step structure formed during growth along positive slope. v and v' are velocities of the steps .

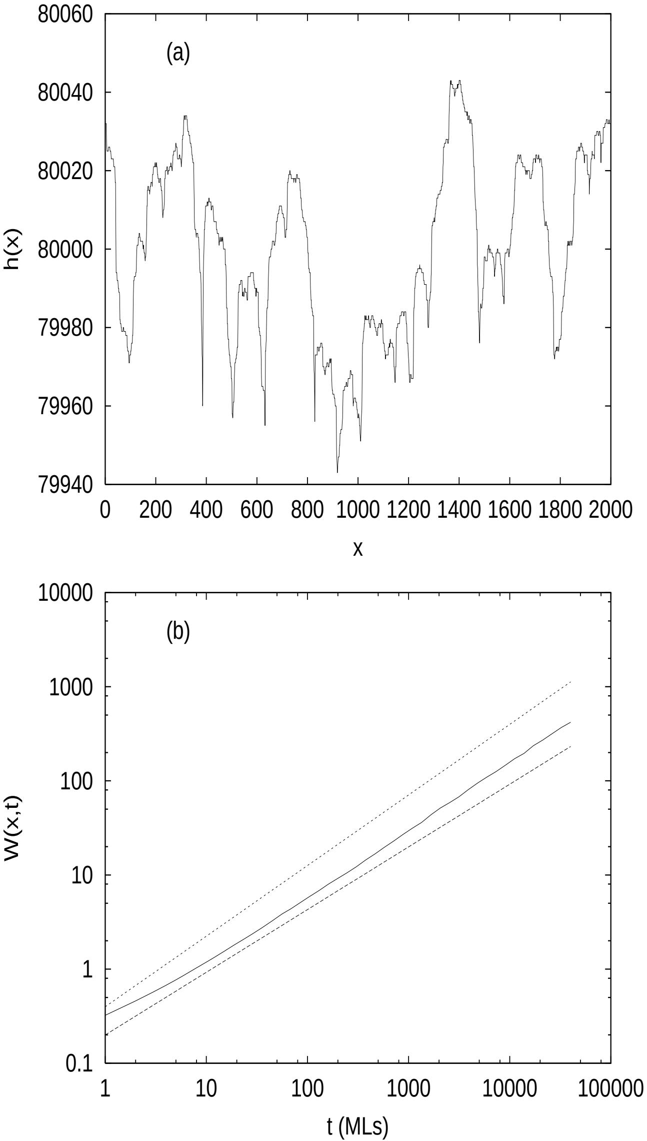

FIG. 2. (a) Morphology of the surface after 80000 number of layers. (b)Plot of width as a function of time. Straight lines with slope 3/4 and 2/3 are drawn for reference.